



50V N-Channel Enhancement Mode MOSFET - ESD Protected

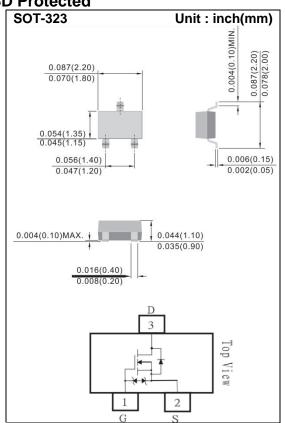
Voltage 50 V Current 360mA

Features

- RDS(ON), VGS@10V, ID@500mA<1.6Ω
- RDS(ON), VGS@4.5V, ID@200mA<2.5Ω
- RDS(ON) , VGS@2.5V, ID@100mA<4.5Ω
- Advanced Trench Process Technology
- Specially Designed for Battery Operated Systems, Solid-State Relays Drivers: Relay, Displays, Memories, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-323 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	50	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	360	mA
Pulsed Drain Current		I _{DM}	1200	mA
Power Dissipation	T _A =25°C	P _D	236	mW
	Derate above 25°C		1.89	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	530	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	50	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.8	1.0	1.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =500mA	-	0.96	1.6	Ω	
		V _{GS} =4.5V,I _D =200mA	-	1.25	2.5		
		V _{GS} =2.5V,I _D =100mA	-	2.73	4.5		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =50V, V_{GS} =0V	-	0.01	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	<u>+</u> 3.0	<u>+</u> 10	uA	
Dynamic							
Total Gate Charge	Q_g	V _{DS} =25V, I _D =250mA, V _{GS} =4.5V ^(Note 1,2)	-	0.63	1	nC	
Gate-Source Charge	Q_gs		-	0.2	-		
Gate-Drain Charge	Q_gd		-	0.23	-		
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	25	50	pF	
Output Capacitance	Coss		-	9.5	20		
Reverse Transfer Capacitance	Crss	I=1.UIVIDZ	-	2.1	5		
Switching							
Turn-On Delay Time	td _(on))/ O5)/ L 500 ·· A	-	2.2	5		
Turn-On Rise Time	tr	V _{DD} =25V, I _D =500mA,		19.2	38	ns	
Turn-Off Delay Time	td _(off)	$V_{GS}=10V$, $R_{G}=6\Omega$ (Note 1,2)		6.2	12		
Turn-Off Fall Time	tf	R _G =012	-	23	50		
Drain-Source Diode							
Maximum Continuous Drain-Source				_	500	mA	
Diode Forward Current	IS	I _S			300	IIIA	
Diode Forward Voltage	V_{SD}	I _S =500mA, V _{GS} =0V		0.86	1.5	V	

NOTES:

- 1. Pulse width < 300 μs, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper





TYPICAL CHARACTERISTIC CURVES

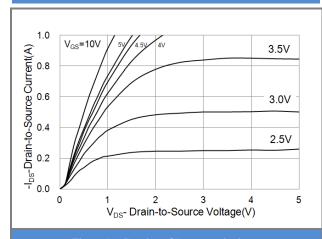


Fig.1 On-Region Characteristics

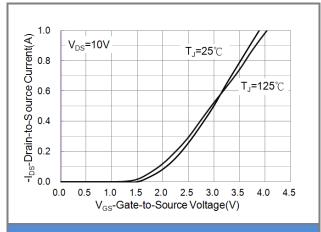


Fig.2 Transfer Characteristics

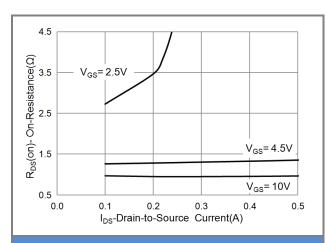


Fig.3 On-Resistance vs. Drain Current

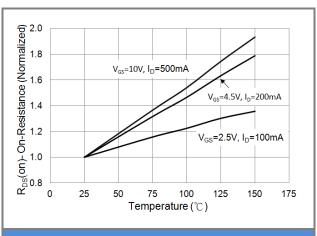


Fig.4 On-Resistance vs. Junction temperature

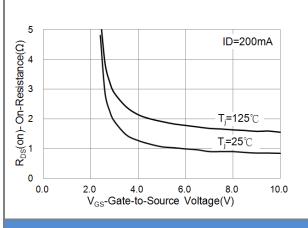


Fig.5 On-Resistance Variation with VGS.

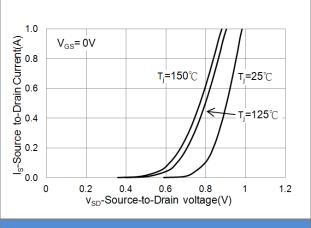


Fig.6 Body Dlode CharacterIslcs





TYPICAL CHARACTERISTIC CURVES

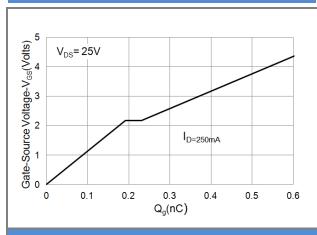


Fig.7 Gate-Charge Characteristics

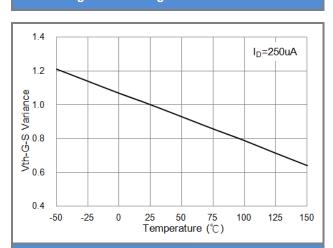


Fig.9 Threshold Voltage Variation with Temperature.

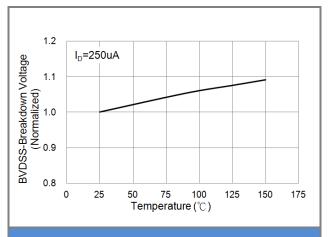


Fig.8 Breakdown Voltage Variation vs. Temperature

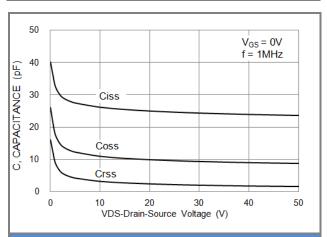


Fig.10 Capacitance vs. Drain-Source Voltage.

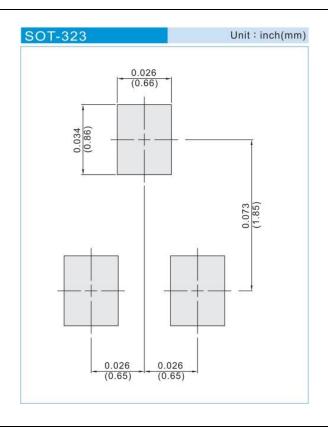




PART NO PACKING CODE VERSION

PART NO PACKING CODE VERSION	Package Type	Packing type	Marking	Version
PJC138K_R1_00001	SOT-323	3K pcs / 7" reel	8KW	Halogen free
PJC138K_R2_00001	SOT-323	12K pcs / 13" reel	8KW	Halogen free

MOUNTING PAD LAYOUT







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